

# LM336-5.0/LM336B-5.0 Programmable Shunt Regulator

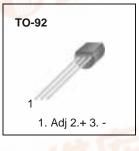
#### Features

- Low Temperature Coefficient
- Adjustable 4V to 6V
- Wide Operating Range Current of 10mA to 400mA
- Three Lead Transistor Package (TO-92)
- 0.6 OHM Dynamic Impedance
- ±1.0% Initial Tolerance Available
- Guaranteed Temperature Stability
- · Easily Trimmed for Minimum Temperature Drift
- Fast Turn On

### Description

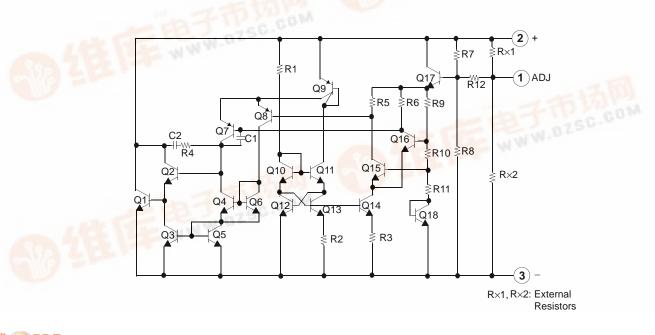
The LM336-5.0 / LM336B-5.0 integrated circuits are precision 5.0V shunt regulators. The monolithic IC voltage reference operates as a low temperature coefficient 5.0V zener with 0.6 ohm dynamic impedance. A third terminal on the LM336-5.0/LM336B-5.0 allows the reference voltage and temperature coefficient to be trimmed easily.

The LM336-5.0/LM336B-5.0 are useful as a precision 5.0V low voltage references which makes it convenient to obtain a stable reference from low voltage supplies. Further, since the LM336-5.0/LM336B-5.0 operate as shunt regulators, they can be used as either a positive or negative voltage reference.





### Internal Block Diagram



## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Reverse Current	IR	15	mA
Forward current	lF	10	mA
Operating Temperature Range LM336/LM336B-0.5	TOPR	0 ~ +70	°C
Storage Temperature Range	TSTG	-60 ~ +150	°C

### **Electrical Characteristics**

 $(0^{\circ}C \le T_A \le +70^{\circ}C$  unless otherwise specified)

Parameter	ameter Symbol Conditions	LM336-5.0		LM336B-5.0			Unit		
Farameter Sym	Symbol	Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage	VR	TA = 25°C, IR = 1mA	4.8	5.0	5.2	4.9	5.0	5.1	V
Reverse Breakdown Change with Current	ΔVR/ΔIR	$T_A = 25^{\circ}C$ 600µA ≤ I <sub>R</sub> ≤ 10mA	-	6	20	-	6	20	mV
Reverse Dynamic Impedance	ZD	TA = 25°C, IR = 1mA	-	0.6	2	-	0.6	2	Ω
Temperature Stability	STT	IR = 1mA	-	4	12	-	4	12	mV
Reverse Breakdown Change with Current	ΔVR/ΔIR	$600 \mu A \le I_R \le 10 m A$	-	6	24	-	6	24	mV
Reverse Dynamic Impedance	ZD	I <sub>R</sub> = 1mA	-	0.8	2.5	-	0.8	2.5	Ω
Long Term Stability In Reference Voltage	ST	I <sub>R</sub> = 1mA	-	20	-	-	20	-	ppm/ Khr

### **Typical Perfomance Characteristics**

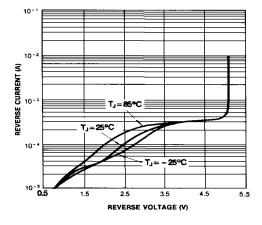


Figure 1. Reverse Characteristics

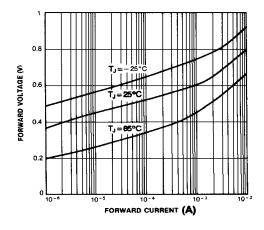


Figure 3. Forward Characteristics

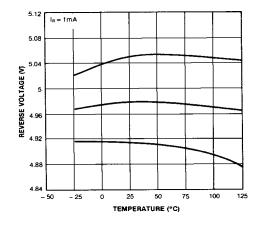


Figure 2. Temperature Drift

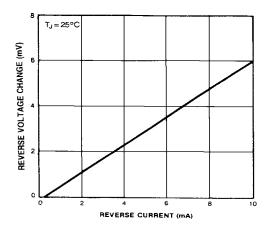
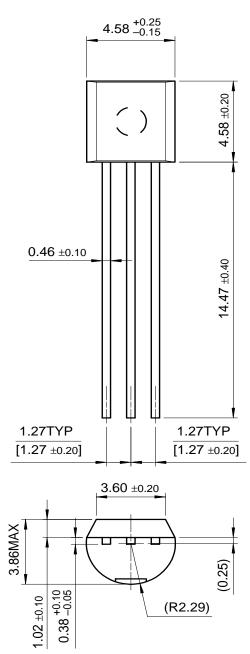


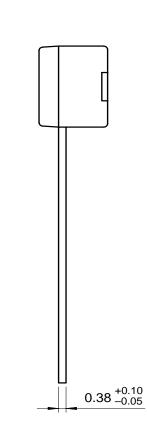
Figure 4. Reverse Voltage Change

#### **Mechanical Dimensions**

#### Package

#### **Dimensions in millimeters**





**TO-92** 

## **Ordering Information**

Product Number	Package	Operating Temperature
LM336Z5	TO-92	0 ~ +70°C
LM336BZ50	10-92	0~+70 0

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